



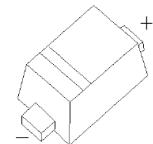
迈拓电子  
MAITUO ELECTRONIC

## 1SS388 SCHOTTKY BARRIER DIODE



### FEATURES

- Small package
- Low forward voltage
- Low reverse current



MARKING: S3

SOD-523

### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit		Unit
Peak reverse voltage	V <sub>RM</sub>	45		V
DC reverse voltage	V <sub>R</sub>	40		V
Maximum (peak) forward current	I <sub>FM</sub>	300		mA
Average forward current	I <sub>o</sub>	100		mA
Non-repetitive Peak Forward Surge Current@t=8.3ms	I <sub>FSM</sub>	1000		mA
Power dissipation	P <sub>D</sub>	150		mW
Operating Junction Temperature Range	T <sub>j</sub>	-40 ~ +125		°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150		°C

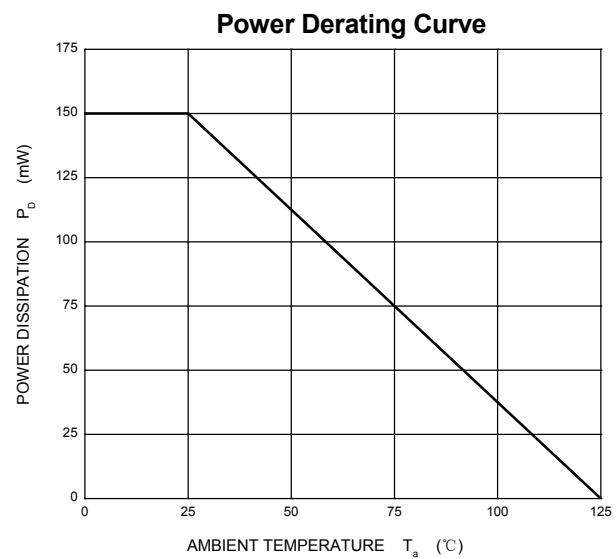
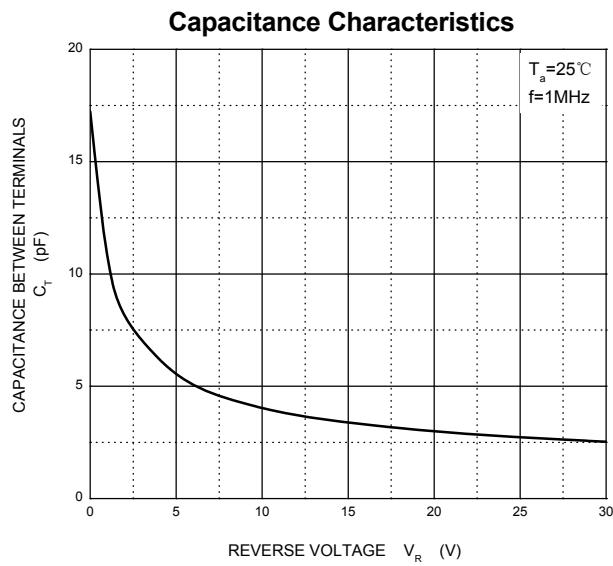
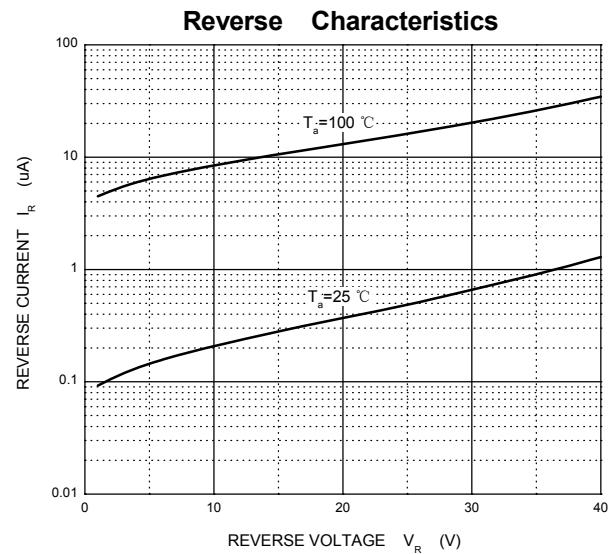
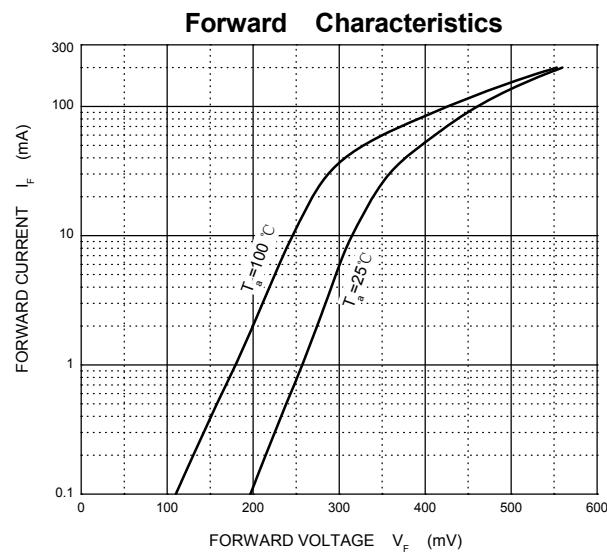
### Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V <sub>F1</sub>		0.28		V	I <sub>F</sub> =1mA
	V <sub>F2</sub>		0.36		V	I <sub>F</sub> =10mA
	V <sub>F3</sub>		0.54	0.60	V	I <sub>F</sub> =50mA
Reverse current	I <sub>R</sub>			5	μ A	V <sub>R</sub> =10V
Total capacitance	C <sub>T</sub>		18	25	pF	V <sub>R</sub> =0,f=1MHz



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## Typical Characteristics



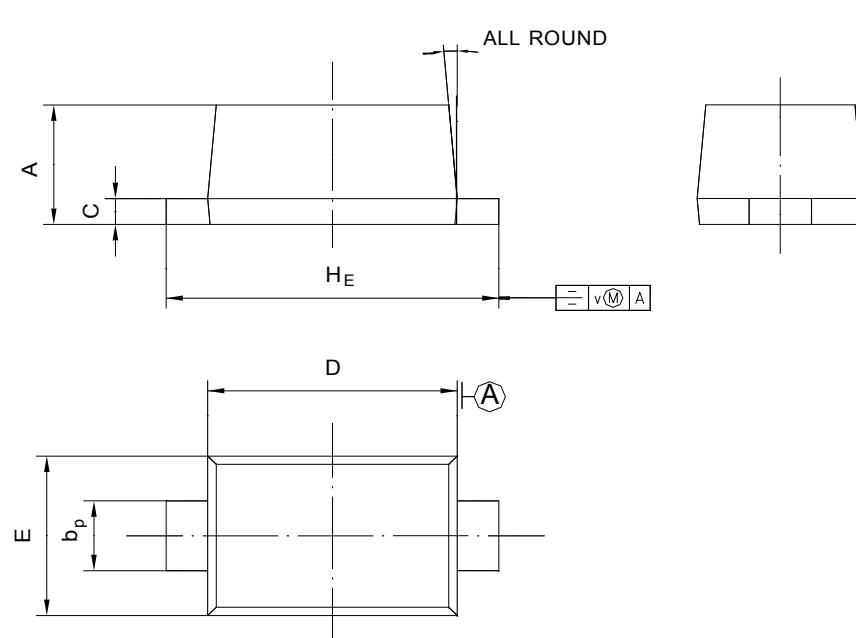


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## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>	V	∠
mm	0.68 0.58	0.4 0.3	0.135 0.100	1.25 1.15	0.85 0.75	1.7 1.5	0.1	5°